

# CBCS Scheme



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15ELN15/25

## First/Second Semester B.E. Degree Examination, June/July 2018 Basic Electronics

Time: 3 hrs.

Max. Marks: 80

Note: Answer any FIVE full questions, choosing one full question from each module.

### Module-1

- Explain the i) Ideal-diode approximation ii) Practical diode approximation iii) Piece-wise linear approximation of diode. (06 Marks)
  - Draw the circuit of full-wave rectifier and derive the expression for average dc current  $I_{DC}$ , RMS load current  $I_{RMS}$ . (08 Marks)
  - Calculate the output voltage  $V_0$  in the following circuit:

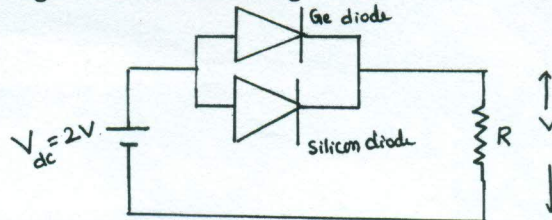


Fig. Q.1(c)

Assume  $V_r$  (breakdown  $V_g$  of  $G_e$ ) = 0.7V

Assume  $V_r$  (breakdown  $V_g$  of silicon) = 0.3V.

(02 Marks)

### OR

- Draw the common Emitter circuit and sketch the output characteristics, explain active region, cut off region and saturation region by indicating them on the characteristic curve. (08 Marks)
  - A transistor has  $I_B = 100\mu A$  and  $I_C = 2mA$ . Find: i)  $\beta$  of the transistor ii)  $\alpha$  of the transistor iii) Emitter current  $I_E$  iv) If  $I_B$  changes by  $+2\mu A$  and  $I_C$  changes by  $+0.6mA$ . Find the new value of  $\beta$ . (08 Marks)

### Module-2

- Sketch a base-bias circuit and write equations for  $I_B$ ,  $I_C$  and  $V_{CE}$ . (04 Marks)
  - A voltage divider bias circuit with a 25V supply has  $R_C = 4.7 K\Omega$ ,  $R_E = 3.3 K\Omega$ ,  $R_1 = 33K\Omega$ ,  $R_2 = 12K\Omega$  and  $h_{FE} = 50$ . Use the approximate analysis method to calculate the  $V_{CE}$  level. (08 Marks)
  - Derive the output equation for non-inverting amplifier using op-amp. (04 Marks)

### OR

- Define the terms: i) Slew rate ii) CMRR iii) Common mode gain  $A_C$ . (06 Marks)
  - Design an adder circuit using op-amp to obtain an output expression  $V_0 = -(0.1V_1 + 0.5V_2 + 20V_3)$  where  $V_1$ ,  $V_2$  and  $V_3$  are the inputs select  $R_f = 10K\Omega$ . (06 Marks)
  - Write any four Ideal-opamp characteristics. (04 Marks)



**Module-3**

- 5 a. Convert the following binary numbers to octal number system:  
 i) 1011.1111                      ii) 11110011110001.                      (04 Marks)  
 b. With a neat diagram, explain the concept of digital waveform.                      (06 Marks)  
 c. Subtract  $(1000.01)_2$  from  $(1011.10)_2$  using 1's and 2's complement method.                      (06 Marks)

**OR**

- 6 a. State and prove De-Morgan's theorem.                      (04 Marks)  
 b. Simplify the following Boolean expressions:  
 i)  $AB + \overline{AC} + A\overline{BC}(AB + C)$                       (06 Marks)  
 ii)  $\overline{\overline{AB} + ABC + A(B + \overline{AB})}$                       (06 Marks)  
 c. Realize full adder circuit using NAND gate.                      (06 Marks)

**Module-4**

- 7 a. Explain the working of clocked R-S flip flop with a suitable circuit, symbol, truth-table, input-output waveforms considering positive edge triggered RS flip-flop.                      (08 Marks)  
 b. With a neat block diagram, explain how stepper motor is interfaced to 8051 microcontroller.                      (08 Marks)

**OR**

- 8 a. With a neat diagram, explain flag register of 8051 microcontroller.                      (06 Marks)  
 b. Differentiate between latches and flip-flops.                      (04 Marks)  
 c. Draw the TMOD register and explain how it control the modes of operation of a timer in 8051 microcontroller.                      (06 Marks)

**Module-5**

- 9 a. Define amplitude modulation and derive the expression for standard amplitude modulation. Also define modulation index.                      (06 Marks)  
 b. A broadcast transmitter radiates 20kW when the modulation percentage is 75. How much of this is carrier power? Also calculate the power of each sideband.                      (06 Marks)  
 c. Distinguish between frequency modulation and amplitude modulation.                      (04 Marks)

**OR**

- 10 a. With a neat diagram, explain the construction and operation of LVDT. Also mention its advantages and disadvantages.                      (10 Marks)  
 b. An FM signal is given as  $V = 12 \sin(5 \times 10^3 t + 5 \sin 1250t)$ . Calculate: i) Carrier frequency ii) Modulating frequency iii) Frequency deviation.                      (06 Marks)

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